## NSN 5961-01-372-9988

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-9988 **Inclosure Material:** Metal **Overall Length:** Between 0.140 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 collector to emitter voltage, dc all transistor and 10.0 collector to base voltage, dc all transistor and 3.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes base current, dc blank all transistor **Power Rating Per Characteristic:** 550.0 milliwatts any acceptable preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: